

2SC4269

VHF Converter, Local Oscillator Applications

Features

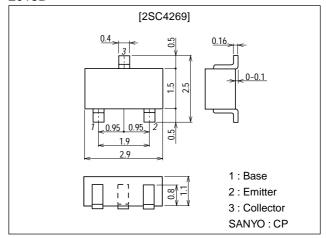
· High power gain : PG=15dB typ (f=0.4GHz)

· High cutoff frequency: f_T=1.2GHz typ

Package Dimensions

unit:mm

2018B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		30	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		3	V
Collector Current	lc		50	mA
Base Current	Ι _Β		20	mA
Collector Dissipation	PC		250	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falantete	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =20V, I _E =0			0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =2V, I _C =0			1	μΑ
DC Current Gain	h _{FE}	V_{CE} =10V, I_{C} =5mA	40*		200*	
Gain-Bandwidth Product	fΤ	V _{CE} =10V, I _C =10mA	0.6	1.2		GHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		0.75	1.1	pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =10V, f=1MHz		0.5		pF
Power Gain	PG	V _{CE} =10V, I _C =10mA, f=0.4GHz		15		dB
Noise Figure	NF	V _{CE} =10V, I _C =3mA, f=0.4GHz		2.0		dB

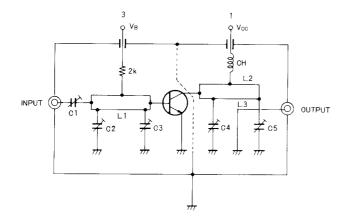
 \ast : The 2SC4269 is classified by 5mA $h_{\mbox{\scriptsize FE}}$ as follows : |

40 2 80 60 3 120 100 4 200

(Note) Marking: JT h_{FE} rank: 2, 3, 4

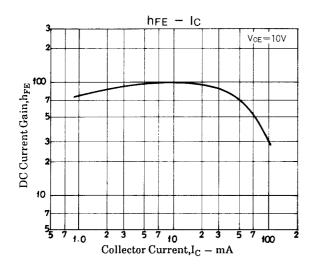
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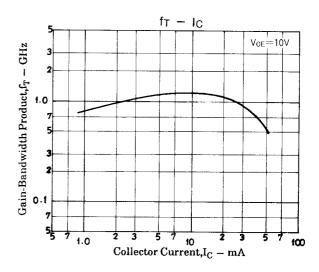
PG, NF Test Circuit

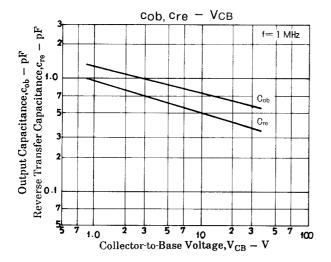


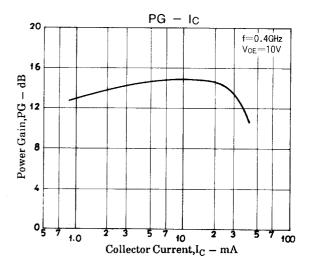
f=400MHz				
~20pF ~10pF ~10pF				
~20pF				
~30pF				
2φ, l=40mm 2/3t				
2φ, l=40mm 2/3t				
1φ, l=40mm 1/2t				

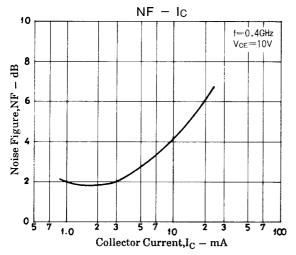
Unit (resistance : Ω)

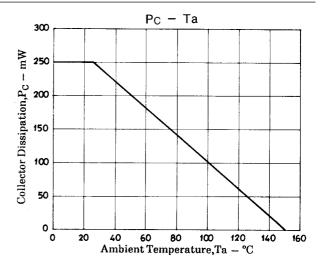






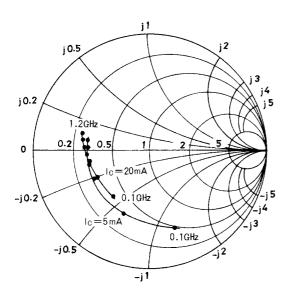




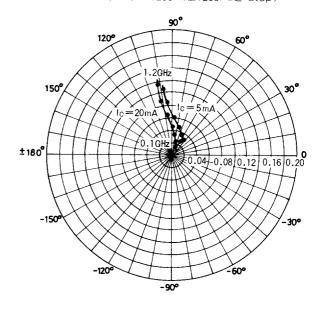


S parameter

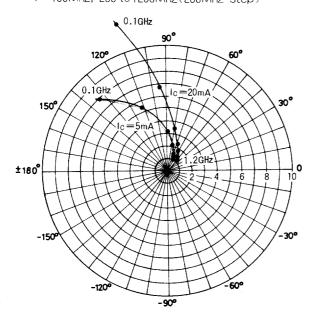
S11e: V_{CE}=10V f=100MHz, 200 to1200MHz(200MHz step)



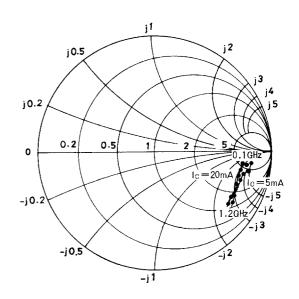
S12e: V_{CE}= 10V f=100MHz, 200 to 1200MHz (200MHz step)



S21e: V_{CE}=10V f=100MHz, 200 to1200MHz(200MHz step)







2SC4269

S parameter (Common emitter)

 $V_{CE}=10V$, $I_{C}=5mA$, $Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.703	-69.5	7.836	133.2	0.022	56.2	0.873	-10.4
200	0.529	-111.8	5.462	111.6	0.029	49.5	0.809	-12.1
400	0.543	-152.3	3.089	89.2	0.036	59.4	0.771	-15.2
600	0.538	-166.4	2.123	78.2	0.046	74.4	0.767	-19.6
800	0.541	-175.3	1.626	69.3	0.061	86.1	0.766	-25.0
1000	0.550	177.0	1.332	63.2	0.082	93.7	0.768	-29.7
1200	0.561	171.4	1.144	57.1	0.107	96.9	0.773	-35.4

 $V_{CE}=10V, I_{C}=20mA, Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.521	-127.8	12.130	109.6	0.014	56.2	0.783	-9.5
200	0.517	-153.4	6.656	94.7	0.020	64.9	0.753	-9.2
400	0.532	-169.8	3.328	79.1	0.032	77.9	0.745	-12.4
600	0.544	-177.2	2.236	69.2	0.047	86.8	0.751	-17.4
800	0.565	176.9	1.655	60.5	0.065	94.8	0.761	-23.1
1000	0.583	172.2	1.334	54.4	0.087	99.7	0.769	-28.1
1200	0.597	167.0	1.129	48.4	0.114	101.2	0.776	-34.0

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